NSN 5961-00-278-9639

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View Online at https://aerobasegroup.com/nsn/5961-00-278-9639 **Inclosure Material:** Metal **Overall Length:** 1.550 inches **Overall Height:** 0.300 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage, dc and 100.0 collector to emitter voltage, dc and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** Between 0.50 amperes source cutoff current and 16.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 07690-429561 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:**

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Demilitarization: Yes - demil/mli